

Low drop power Schottky rectifier

Main product characteristics

I _{F(AV)}	2 A
V _{RRM}	30 V
T _j (max)	150° C
V _F (max)	0.375 V

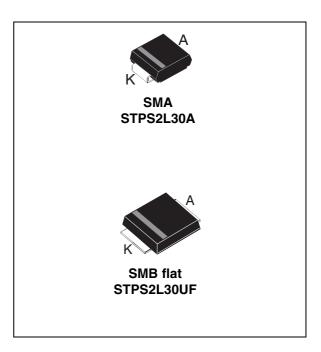
Features and benefits

- Low cost device with low drop forward voltage for less power dissipation
- Optimized conduction/reverse losses trade-off which lead to the highest yield in the applications
- Surface mount miniature packages
- Avalanche capability specified

Description

Single Schottky rectifier suited to switched mode power supplies and high frequency DC to DC converters, freewheel diode and integrated circuit latch up protection.

Packaged in SMA and low profile SMB, this device is especially intended for use in parallel with MOSFETs in synchronous rectification.



Order codes

Part Number	Marking
STPS2L30A	G30
STPS2L30UF	FG30

Table 1. Absolute ratings (limiting values)

Symbol	Parameter			Value	Unit
V _{RRM}	Repetitive peak reverse volt	Repetitive peak reverse voltage			
1	A	SMA	T _L = 120° C δ = 0.5	2	Α
lF(AV)	Average forward current	SMB flat	$T_L = 135^{\circ} \text{ C } \delta = 0.5$		
I _{FSM}	Surge non repetitive forward current t _p =10 ms sinusoidal		75	Α	
P _{ARM}	Repetitive peak avalanche power $t_p = 1 \mu s Tj = 25^{\circ} C$			1500	W
T _{stg}	Storage temperature range			-65 to + 150	°C
Tj	Operating junction temperature (1)			150	°C

^{1.} $\frac{dPtot}{dT_i} < \frac{1}{Rth(i-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

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1 Characteristics

Table 2. Thermal resistance

Symbol	Parameter	Parameter		
В	lunation to load	SMA	30	°C/W
R _{th(j-l)} Junction to lead	Surremon to lead	SMB flat	15	C/VV

Table 3. Static electrical characteristics

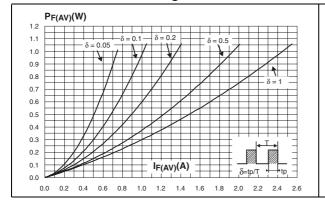
Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
ı (1)	I _R ⁽¹⁾ Reverse leakage current	T _j = 25° C	$V_R = V_{RRM}$			200	μΑ
IR' / R		T _j = 100° C			6	15	mA
	T _j = 25° C			0.45			
V _E ⁽¹⁾	Forward voltage drop	I voltage drop		0.325	0.375	V	
VF`	Polward voltage drop				0.53	V	
		T _j = 125° C	- I _F = 4 A		0.43	0.51	

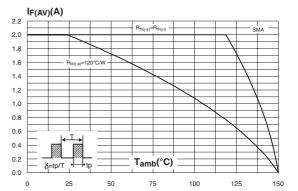
^{1.} Pulse test: tp = 380 μ s, δ < 2%

To evaluate the conduction losses use the following equation:

 $P = 0.24 \times I_{F(AV)} + 0.068 I_{F}^{2}(RMS)$

Figure 1. Average forward power dissipation Figure 2. Average forward current versus versus average forward current ambient temperature (δ = 0.5) SMA





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Figure 3. Average forward current versus ambient temperature (δ = 0.5) SMB flat

| F(AV)(A) | 2.2 | 2.0 | Reng-syl=Reng-ty | 2.2 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 | 2.0 |

Figure 4. Non repetitive surge peak forward current versus overload duration (maximum values) SMA

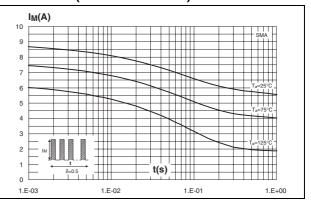
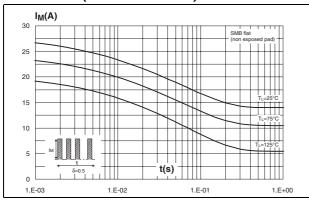


Figure 5. Non repetitive surge peak forward current versus overload duration (maximum values) SMB flat

Figure 6. Normalized avalanche power derating versus pulse duration



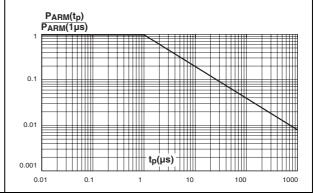
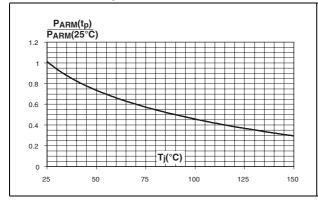
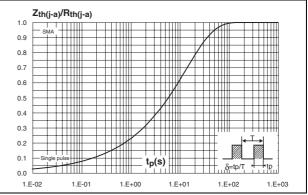


Figure 7. Normalized avalanche power derating versus junction temperature

Figure 8. Relative variation of thermal impedance, junction to ambient, versus pulse duration - SMA

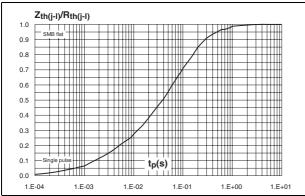




Characteristics STPS2L30

Figure 9. Relative variation of thermal impedance junction to lead versus pulse duration - SMB flat

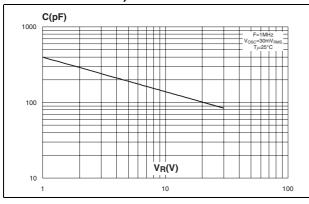
Figure 10. Reverse leakage current versus reverse voltage applied (typical values)



1.E+01
1.E+01
1.E+00
1.E-01
1.E-02
0 5 10 15 20 25 30

Figure 11. Junction capacitance versus reverse voltage applied (typical values)

Figure 12. Forward voltage drop versus forward current (maximum values, high level)



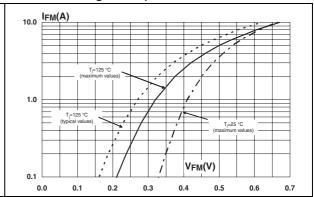
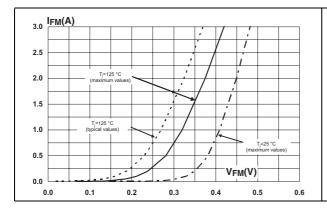
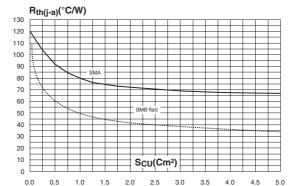


Figure 13. Forward voltage drop versus forward current (maximum values, low level)

Figure 14. Thermal resistance junction to ambient versus copper surface under each lead (epoxy printed board FR4, e_{CU} = 35 μ m)





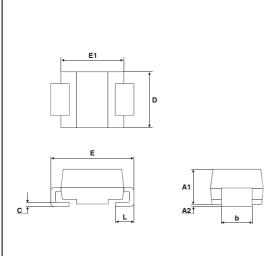
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STPS2L30 Package Information

2 Package Information

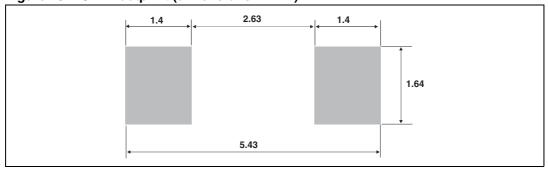
Epoxy meets UL94, V0

Table 4. SMA dimensions



	Dimensions				
Ref.	Millimeters		Inc	hes	
	Min.	Max.	Min.	Max.	
A1	1.90	2.45	0.075	0.094	
A2	0.05	0.20	0.002	0.008	
b	1.25	1.65	0.049	0.065	
С	0.15	0.40	0.006	0.016	
D	2.25	2.90	0.089	0.114	
Е	4.80	5.35	0.189	0.211	
E1	3.95	4.60	0.156	0.181	
L	0.75	1.50	0.030	0.059	

Figure 15. SMA footprint (dimensions in mm)



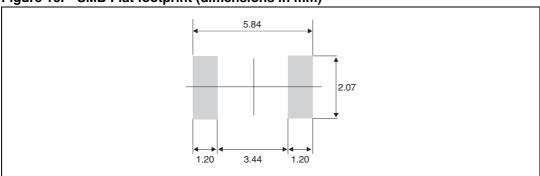
Package Information STPS2L30

Table 5. SMB Flat dimensions

				Dim	ensions	•	
	Ref.	Mi	illimet	ers		Inches	
A T		Min.	Тур.	Max.	Min.	Тур.	Max.
D A C -	Α	0.90		1.10	0.035		0.043
<u> </u>	b ⁽¹⁾	1.95		2.20	0.077		0.087
L\$ L2	c ⁽¹⁾	0.15		0.40	0.006		0.016
E E1	D	3.30		3.95	0.130		0.156
	Е	5.10		5.60	0.200		0.220
L1	E1	4.05		4.60	0.189		0.181
<u></u>	L	0.75		1.50	0.029		0.059
	L1		0.40			0.016	
	L2		0.60			0.024	

^{1.} Applies to plated leads

Figure 16. SMB Flat footprint (dimensions in mm)



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

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3 Ordering information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS2L30A	G30	SMA	0.068 g	5000	Tape and reel
STPS2L30UF	FG30	SMB flat	0.50 g	5000	Tape and reel

4 Revision history

Date	Revision	Description of Changes
Jul-2003 3A Last update.		Last update.
Aug-2004 4		SMA package dimensions update. Reference A1 max. changed from 2.70mm (0.106inc.) to 2.03mm (0.080).
31-Jan-2007	5	Reformatted to current standard. Added ECOPACK statement. Added SMB flat package.

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